Vishay Semiconductors

## High Voltage Surface Mount Input Rectifier Diode, 25 A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	25 A				
V <sub>R</sub>	800 V, 1000 V, 1200 V				
V <sub>F</sub> at I <sub>F</sub>	1.14 V				
I <sub>FSM</sub>	300 A				
T <sub>j</sub> max.	150 °C				
Package	D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Single				

### FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to  ${\sf JEDEC^{\circledast}}\text{-}{\sf JESD}$  47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### APPLICATIONS

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

### DESCRIPTION

The VS-25ETS..S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	20	23	A		

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>F(AV)</sub>	Sinusoidal waveform	25	A				
V <sub>RRM</sub>		800 to 1200	V				
I <sub>FSM</sub>		300	A				
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.0	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS			
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA
VS-25ETS08S-M3	800	900	
VS-25ETS10S-M3	1000	1100	1
VS-25ETS12S-M3	1200	1300	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	$T_{\rm C}$ = 106 °C, 180° conduction half sine wave	25			
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V <sub>RRM</sub> applied	250	А		
	I <sub>FSM</sub>	10 ms sine pulse, no voltage reapplied	ed 300			
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	316	A <sup>2</sup> s		
	1-1	10 ms sine pulse, no voltage reapplied	442	A-2		
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	MBOL TEST CONDITIONS VALUES UNITS					
Maximum forward voltage drop	V <sub>FM</sub>	25 A, T <sub>J</sub> = 25 °C		1.14	V		
Forward slope resistance	r <sub>t</sub>	T.I = 150 °C	9.62	mΩ			
Threshold voltage	V <sub>F(TO)</sub>	1j = 150 C	0.87	V			
Maximum reverse leakage current	I	T <sub>J</sub> = 25 °C	$V_{B} = Rated V_{BBM}$	0.1	mA		
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR = naied VRRM	1.0	ША		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	)	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C	
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.9		
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		62	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque maximum				12 (10)	(lbf ⋅ in)	
				25ET	S08S	
Marking device			Case style D <sup>2</sup> PAK (TO-263AB)	25ETS10S		
				25ET	S12S	

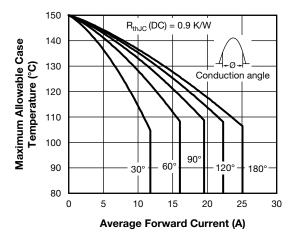
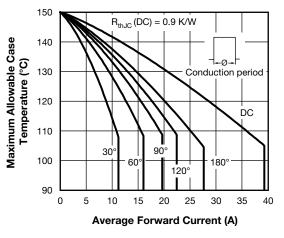
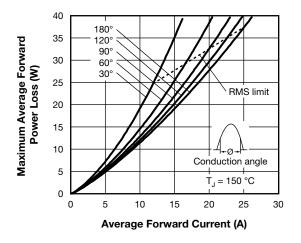


Fig. 1 - Current Rating Characteristics





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Fig. 3 - Forward Power Loss Characteristics

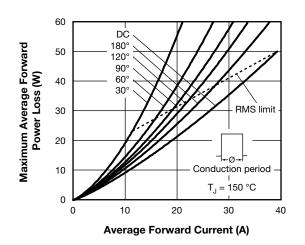


Fig. 4 - Forward Power Loss Characteristics

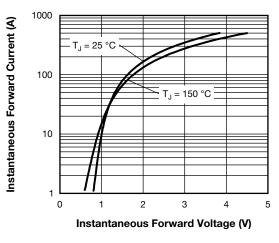
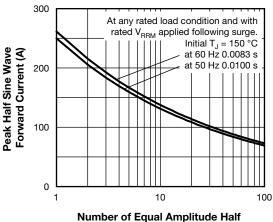


Fig. 7 - Forward Voltage Drop Characteristics



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

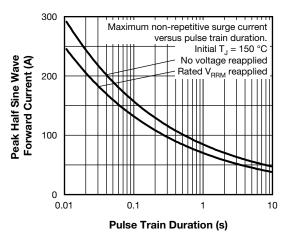
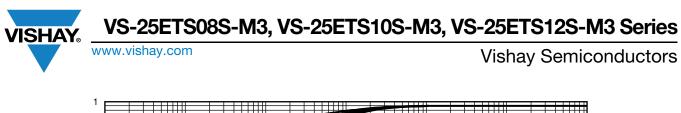


Fig. 6 - Maximum Non-Repetitive Surge Current

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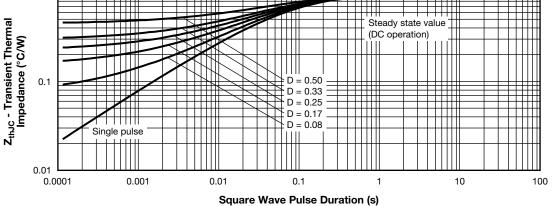


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

Device code	VS-	25	Е	т	S	12	S	TRL	-МЗ
I	1	2	3	4	5	6	7	8	9
	1 - 2 - 3 - 4 -	Cur Circ E Pac	rent rati cuit conf = single kage:	niconduc ng (25 = iguration e K (TO-2	= 25 A) n	oduct			
     	5 - 6 - 7 - 8 - 9 -	S Volt S = • No • TF • TF	age coo surface one = tu RL = tap RR = tap	ard reco le x 100 mounta	= V <sub>RRM</sub> ble eel (left o eel (righ	orientec	ed)	12 = 1	000 V 200 V

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ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-25ETS08S-M3	50	Antistatic plastic tube				
VS-25ETS08STRR-M3	800	13" diameter reel				
VS-25ETS08STRL-M3	800	13" diameter reel				
VS-25ETS10S-M3	50	Antistatic plastic tube				
VS-25ETS10STRR-M3	800	13" diameter reel				
VS-25ETS10STRL-M3	800	13" diameter reel				
VS-25ETS12S-M3	50	Antistatic plastic tube				
VS-25ETS12STRR-M3	800	13" diameter reel				
VS-25ETS12STRL-M3	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96164				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				

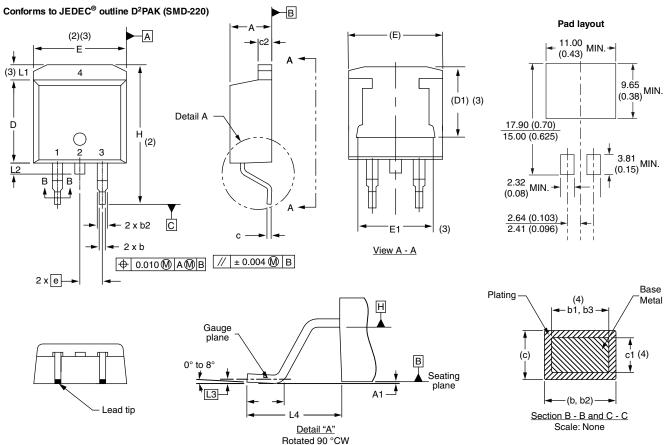
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D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches

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ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

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#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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